TOSHIBA Transistor Silicon NPN Triple Diffused Type

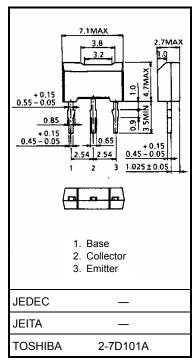
2SC6042

High-Speed, High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- High-speed switching: $t_f = 0.2 \ \mu s \ (max) \ (I_C = 0.3A)$
- High breakdown voltage: $V_{CES} = 800 \text{ V}, V_{CEO} = 375 \text{ V}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	800	V	
Collector-emitter voltage		V _{CES}	800	V	
		V _{CEO}	375	V	
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	ΙC	1.0	A	
	Pulse	I _{CP}	2.0		
Base current		Ι _Β	0.5	А	
Collector power dissipation	Ta = 25°C	P _C	1.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.2 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

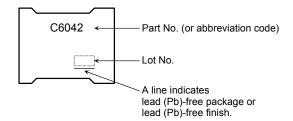
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

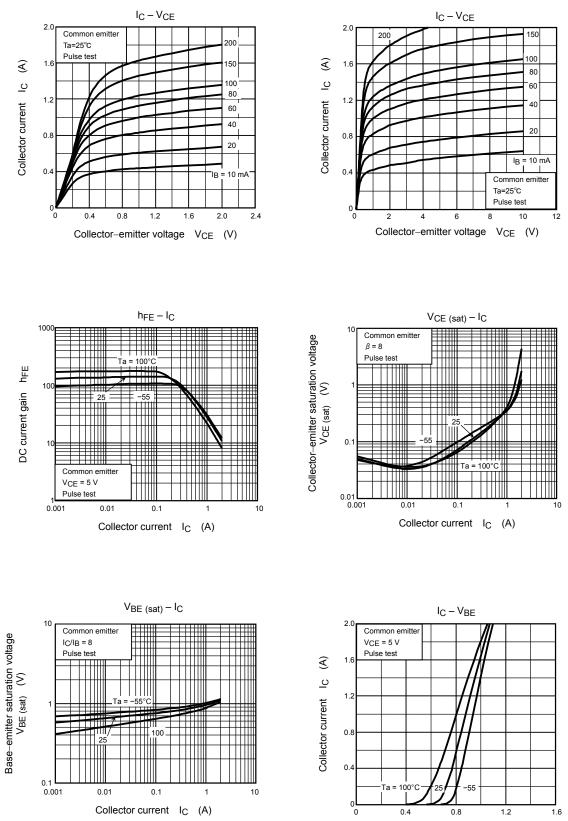
Electrical Characteristics (Ta = 25°C)

Char	acteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 800 V, I _E = 0		—	100	μA
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	-	_	100	μA
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _B = 0	800	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	375	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	80	—	_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.1 A	100	_	200	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 0.2 A	80	—	_	
Collector emitter saturation voltage		V _{CE (sat)}	I _C = 0.8 A, I _B = 0.1 A	_	_	1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.8 A, I _B = 0.1 A		—	1.3	V
Switching time Storag	Rise time	tr	20 µs V _{CC} ≈ 200 V	_	_	0.5	
	Storage time	t _{stg}		_	_	4.5	μs
	Fall time	tf	I _{B1} = 20 mA, −I _{B2} = 50 mA DUTY CYCLE ≤ 1%	_	_	0.2	

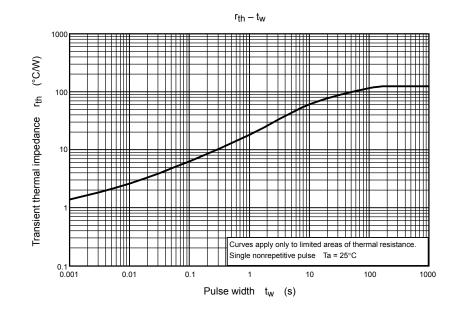
Marking

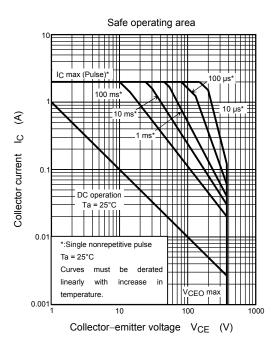


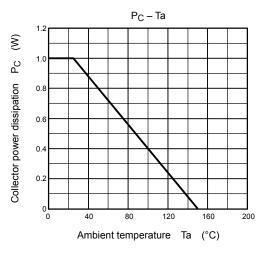
TOSHIBA



Base-emitter voltage VBE (V)







RESTRICTIONS ON PRODUCT USE

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
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